



N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
 - $38 \text{ m}\Omega @ V_{GS} = 10V$
 - 64 mΩ @ V_{GS} = 4.5V
- Low Input Capacitance
- Fast Switching Speed
- Lead Free By Design/RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

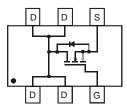
Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.015 grams (approximate)

SOT-26



TOP VIEW



TOP VIEW Internal Schematic

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V _{DSS}	30	V
Gate-Source Voltage	V _{GSS}	±20	V
Drain Current (Note 1)	I _D	4.0	А
Pulsed Drain Current (Note 1)	I _{DM}	16	А

Thermal Characteristics

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 1)	P _D	900	mW
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	139	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

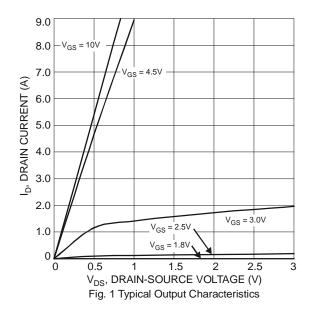
- 1. Device mounted on FR-4 PCB, minimum recommended pad layout on 2oz. Copper pads.
- 2. No purposefully added lead.
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

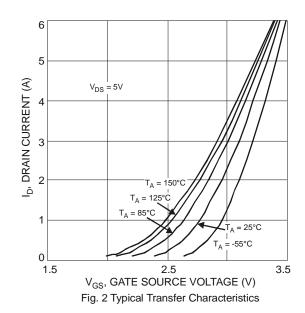


Electrical Characteristics @T_A = 25°C unless otherwise specified

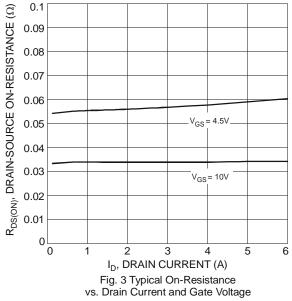
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 4)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	800	nA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage		_	_	±80	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
•	I _{GSS}	_	_	±800	ш	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(th)}	1.2	1	2.2	٧	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	0		28	38	mΩ	$V_{GS} = 10V, I_D = 6A$	
Static Dialii-Source Off-Resistance	R _{DS} (ON)	_	50	64	1112.2	$V_{GS} = 4.5V, I_D = 5A$	
Forward Transfer Admittance	Y _{fs}	_	5.2	_	S	$V_{DS} = 5V, I_{D} = 3.1A$	
Diode Forward Voltage (Note 4)	V _{SD}	_	0.78	1.16	V	$V_{GS} = 0V$, $I_S = 2A$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{iss}		424	_	pF		
Output Capacitance	Coss	_	115	_	pF	$V_{DS} = 5V, V_{GS} = 0V, f = 1.0MHz$	
Reverse Transfer Capacitance	C _{rss}	_	81	_	pF		
Gate Resistance	R_{G}	_	1.3	_	Ω	$V_{GS} = 0V V_{DS} = 0V, f = 1MHz$	
SWITCHING CHARACTERISTICS							
Total Cata Charge	0	_	4.3		nC	$V_{DS} = 10V, V_{GS} = 4.5V, I_{D} = 10A$	
Total Gate Charge	Q_g		8.6	_		$V_{DS} = 10V, V_{GS} = 10V, I_{D} = 10A$	
Gate-Source Charge	Q_{gs}		1.2		iiC	$V_{DS} = 10V, V_{GS} = 10V, I_{D} = 10A$	
Gate-Drain Charge	Q_{gd}		2.5	_		$V_{DS} = 10V, V_{GS} = 10V, I_{D} = 10A$	

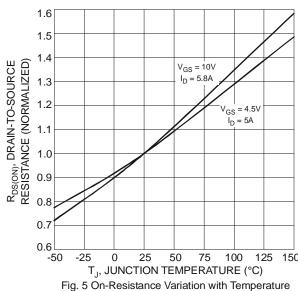
Notes: 4. Short duration pulse test used to minimize self-heating effect.

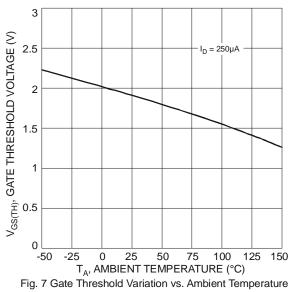














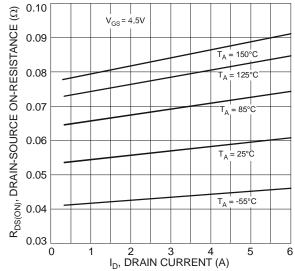
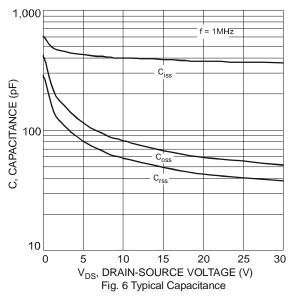
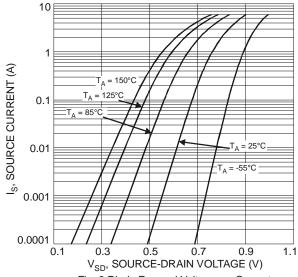


Fig. 4 Typical Drain-Source On-Resistance vs. Drain Current and Temperature





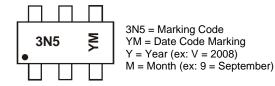


Ordering Information (Note 5)

Part Number	Case	Packaging
DMN3051LDM-7	SOT-26	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

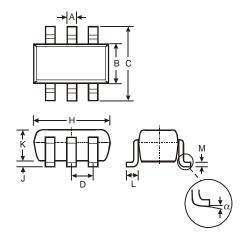
Marking Information



Date Code Key

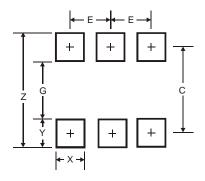
Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	X		Υ	Z		Α	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Package Outline Dimensions



SOT-26					
Dim	Min	Max	Тур		
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
C	2.70	3.00	2.80		
D	_		0.95		
Н	2.90	3.10	3.00		
7	0.013	0.10	0.05		
K	1.00	1.30	1.10		
١	0.35	0.55	0.40		
М	0.10	0.20	0.15		
α	0°	8°	_		
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Y	0.80
С	2.40
E	0.95



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